

BlueX Microelectronics Co., Ltd.

Bluetooth 5.0 LE | MESH SoC

Datasheet of RF08 (with 8Mb Flash)

DS-RF08-01

Version 3.4

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http://www.bluexmicro.com



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1 General description

The RF08 is a System-on-Chip combining an application processor, memories, cryptography engine, power management unit, digital and analog peripherals and a MAC engine complied with Bluetooth® Low Energy 5.0 and radio transceiver.

A 32-bit MCU is integrated in RF08 for BLE link layer management and system operation. Rich digital and analog peripheral interfaces are optimized for external control, including GPIO, SPI, UART, IIC, PWM, ADC and LDOs. Power Management Unit with on-chip DCDC buck converter and various Regulators provides ultra-low current consumption for RF08.



2 Feature list

Complies with Bluetooth 5.0 with 1M / 2M bps data rates.

■ Radio Transceiver

- -93 dBm RX sensitivity at 1Mbps mode
- -90 dBm RX sensitivity at 2Mbps mode
- RF output power levels: -20dBm, 0dBm, 3dBm and 8dBm
- 50dB RSSI dynamic range

■ Supply Current

- 4.3mA in RX and 4.4mA in TX with On Chip DCDC Converter@4.3V
- 5.5mA in RX and 5.7mA in TX with On Chip DCDC Converter@3.3V

■ Ultralow Current Mode

- Sleep current: 2.5uA ~ 6uA, SRAM (16 KB ~ 208 KB) retention
- Average current: 20uA, during 1.28 sec cycle time (Active / Sleep)
 Notice: Active (Broadcasting ADV) / Sleep (208 KB SRAM retention)

Analog Interfaces

- 1 Battery monitoring function from 5.5V to 2.0V
- 3 External channel of ADC (ENOB = 10) with average capability (Oversampling up to ENOB = 12)
- Temperature sensor from -40°C to 125°C

■ Digital Interfaces

- Up to 18 GPIOs
- 1 Internal Quad-SPI Flash interface
- 1 General SPI interface
 - Support both SPIM / SPIS Mode
- 2 UART Flow control up to 1Mbps and supports all the baud rate under 1Mbps, IRDA is supported
- 2 IIC Master / Slave programmable and speed up to 1Mbps
- 2 Timers and 1 Watch-dog Timer
- 5 PWM Outputs

■ Integrated 32-bit MCU

- Clock frequency: 16MHz, 32MHz (Major), 48MHz, 64MHz, 80MHz and 96MHz (Max)
- CPU Benchmarking: 2.07 Coremark / MHz
- SWD debug interface
- AHB / APB bus matrix with speed up to 96MHz

■ Memories

- 128 KB ROM (Boot ROM and BLE stack)
- 1 MB Flash
- 208 KB SRAM
 - Composed of 6 pages of 32KB and 1 page of 16KB, with retention capability
 - Each 32KB can be set into retention state separately and exchange memory for BLE connection data
 - 16KB of 4 way cache controller for external SPI flash which enable CPU run on the external SPI flash, this 16KB cache can be also used as system SRAM when cache is disabled



■ Power Management

- 2.3-5.0V power input
- One 1.2V Integrated DCDC buck converter
- One 1.8V LDO with 40mA output
- Two 3.3V LDO with 50mA & 25mA output each

■ Cryptographic Engine

- ECC
- AES-128

■ Package

• QFN48 (6 X 6 mm²)

Operating Temperature

• -25°C to 85°C



3 Package

3.1 RF08 -- QFN 48 pins Package (6 mm x 6 mm) with 8Mb Flash

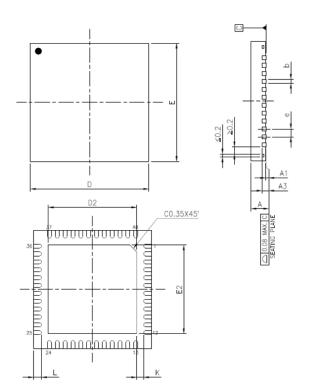
Pin	Symbol	Туре	Description
1	P02	DIO	spim0_cs1/FUNC_IO00/GPIO02
2	P03	DIO	spim0_cs0/SPIS_CS/FUNC_IO01/GPIO03
3	P04	DIO	spim0_clk/SPIS_CLK/FUNC_IO02/GPIO04
4	P05	DIO	spim0_miso/SPIS_MISO/FUNC_IO03/GPIO05
5	P06	DIO	spim0_mosi/SPIS_MOSI/FUNC_IO04/GPIO06
6	P15	DIO	FUNC_IO13/GPIO15
7	P16	DIO	FUNC_IO14/GPIO16
8	P17	DIO	FUNC_IO15/GPIO17
9	P08	DIO	spim1_cs0/FUNC_IO06/GPIO08
10	P10	DIO	spim1_miso/FUNC_IO08/GPIO10
11	P11	DIO	spim1_mosi/FUNC_IO09/GPIO11
12	P12	DIO	FUNC_IO10/GPIO12
13	P13	DIO	FUNC_IO11/GPIO13
14	VDD_SRAM	РО	VDD_SRAM output
15	VDD_3V_1	РО	Supply to external 3.3V
16	VDD_1V8	РО	Supply to external 1.8V
17	VDD_DIG	PI	Digital circuit power supply
18	GND_D	GND	Ground for digital circuit
19	VDD_1V2	РО	DC/DC Converter output
20	VDD_BAT	PI	Battery supply voltage
21	VDD_BUS	N/A	N/A. Floating.
22	Ext Reset	DI	Pull low internally. High active.
23	P00	DIO	swck/GPIO00
24	P01	DIO	swd/GPIO01
25	VDD_CPU	РО	VDD_CPU output

Pin	Symbol	Туре	Description	
26	VDD_AWO	РО	VDD_AWO output	
27	P21	DIO	FUNC_IO19/GPIO21	
28	P22	DIO	FUNC_IO20/GPIO22	
29	P23	DIO	FUNC_IO21/GPIO23	
30	XTAL32K_P	Al	32.768 kHz Crystal input (+)	
31	XTAL32K_N	Al	32.768 kHz Crystal input (-)	
32	VDD_3V_2	РО	Supply to external 3.3V	
33	VDD_BAT_2	PI	Guard ring power supply	
34	VDD_VCO	PI	VCO power supply	
35	LOOP_C	AIO	PLL loop filter external capacitor.	
36	VDD_CP	PI	PLL power supply	
37	PA_Output	РО	8dBm TX Output	
38	VDD_RF1	PI	RF power supply	
39	RF_P	AIO	RF input/output	
40	RF_N	AIO	RF input/output	
41	VDD_A	PI	Power supply for an analog circuit	
42	VDD_BAT_1	PI	ADC power supply	
43	P30	Al	ADC Input Channel 0	
44	P32	Al	ADC Input Channel 2	
45	P34	Al	ADC Input Channel 4	
46	NC	N/A	N/A. Floating.	
47	XTAL32M_P	Al	32 MHz Crystal input (+)	
48	XTAL32M_N	Al	32 MHz Crystal input (-)	
10.			Backside GND plane. Must be	
	Ground pad	GND	connected to the GND.	

 $NOTE: \quad AI: analog \ input \quad AO: analog \ output \quad AIO: analog \ input/output \quad DI: digital \ input \\ \quad DIO: digital \ input/output \quad PI: power \ input \\ \quad PO: power \ output \\ PO: power \ output \\ \quad PO:$

N/A: not available

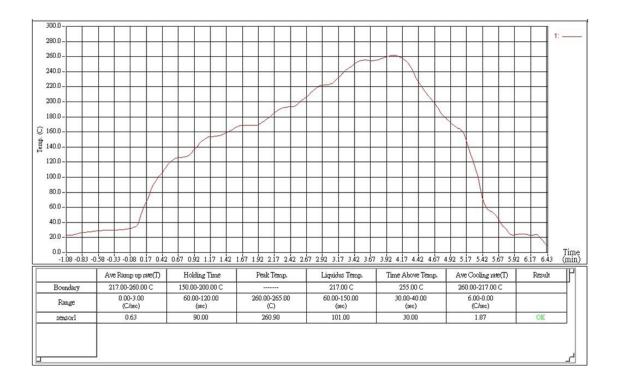




PKG CODE	VQFN				
SYMBOLS	MIN.	NOM.	MAX.	UNIT	
Α	0.80	0.85	0.90		
A1	0.00	0.02	0.05		
A3		0.203 RE	F		
b	0.15	0.20	0.25		
D		6.00 BSC	,	mm	
E		6.00 BSC	;		
e		0.40 BSC	,		
K	0.20	-	-		
Lead Frame PAD SIZE	185 X 18* MIL				
SYMBOLS	MIN.	NOM.	MAX.	UNIT	
D2	4.45	4.50	4.55		
E2	4.45	4.50	4.55	mm	
L	0.35	0.40	0.45		



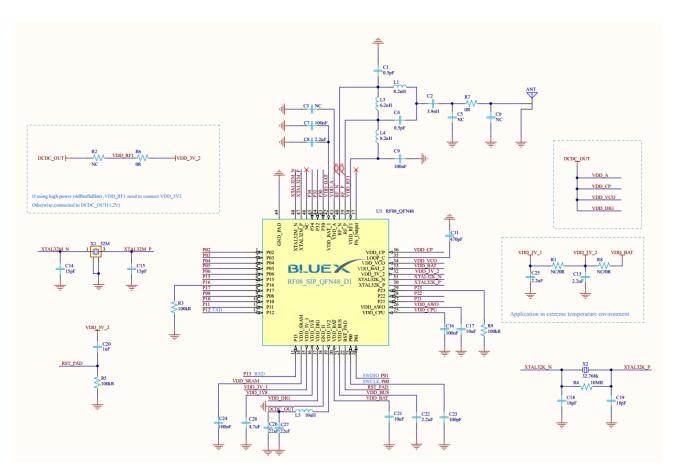
3.2 IR Reflow Temperature-Time Profile





3.3 Application circuit

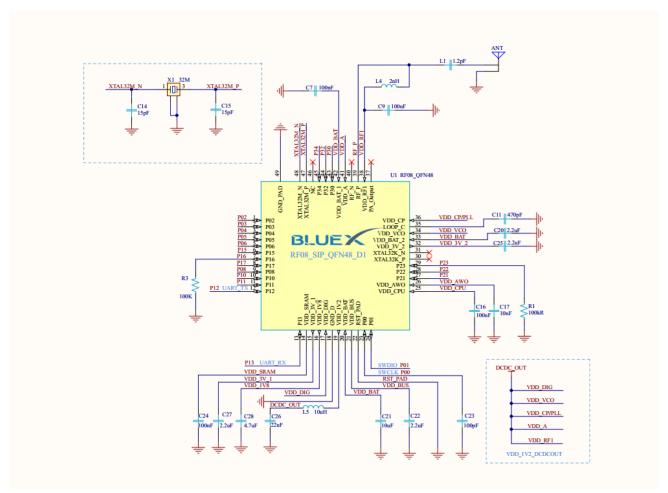
3.3.1 General application circuit



Component	TX PWR.	RX SEN.	LXT	RF CKT. Structure	
Standard: 35 PCS	O dDms/Mass	1Mbps: -93 dBm	Ontion	Differential	
Option : Add 2 PCS	+8 dBm(Max.)	2Mbps: -90 dBm	Option	Differential	



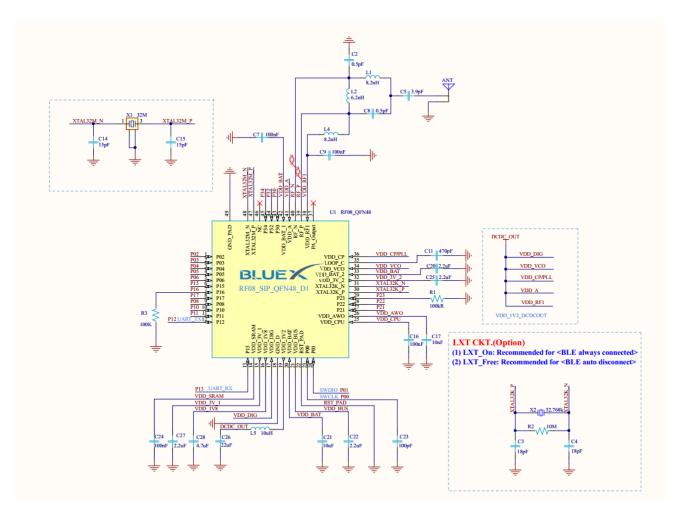
3.3.2 Single-End with DC/DC Bucker available, TX PWR: -3dBm (Max)



Component	TX PWR.	RX SEN.	LXT	RF CKT. Structure
22 PCS	2 dDm/May/)	1Mbps: -90 dBm	LVT from	Cinale End
	-2 dBm(Max.)	2Mbps: -86 dBm	LXT - free	Single-End



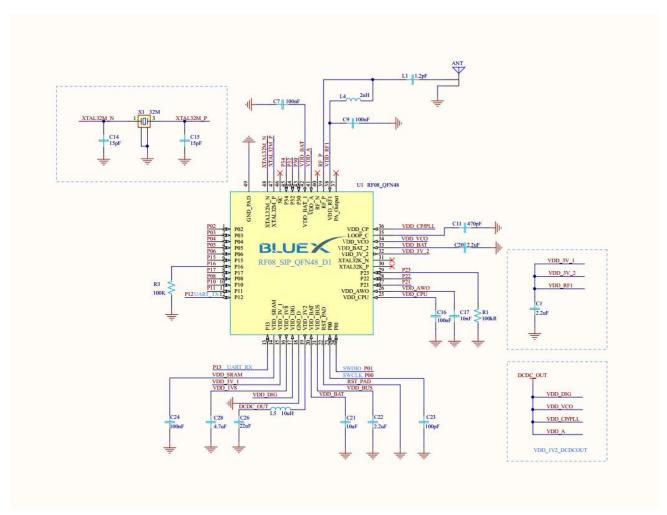
3.3.3 Differential with DC/DC Bucker available, TX PWR: +2dBm(Max)



Component	TX PWR.	RX SEN.	LXT	RF CKT. Structure
Standard: 30 PCS	. 2. dD(M)	1Mbps: -93 dBm	0-6	Differential
Option : Reduce 4 PCS	+2 dBm(Max.)	2Mbps: -90 dBm	Option	Differential



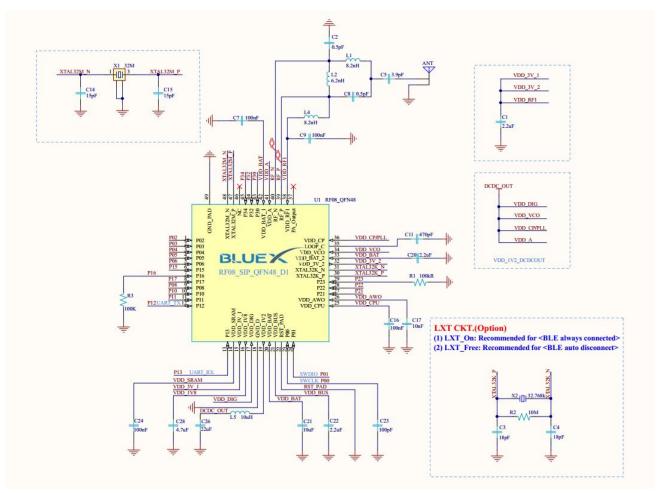
3.3.4 Single-End with DC/DC Bucker available, TX PWR: +4dBm(Max)



Component	TX PWR.	RX SEN.	LXT	RF CKT. Structure
21 PCS	4 dDm(Max)	1Mbps: -90 dBm	LVT from	Cinalo End
	+4 dBm(Max.)	2Mbps: -86 dBm	LXT - free	Single-End



3.3.5 Differential with DC/DC Bucker available, TX PWR: +8dBm(Max)



Circuit Features

Component	TX PWR.	RX SEN.	LXT	RF CKT. Structure	
Standard: 29 PCS	+8 dBm(Max.)	1Mbps: -93 dBm	Option	Differential	
Option : 4 Reduce PCS	+6 ubili(Max.)	2Mbps: -90 dBm	Ориоп	Differential	

4 System overview

4.1 Electronical Characteristics

4.1.1 Absolute maximum ratings

Parameters	Min	Max	Unit
Storage temperature	-40	+120	°C
Voltage applied to inputs	-0.5	+5.5	V



4.1.2 Recommended Operating Conditions

Parameters	Min	Тур	Max	Units
Ambient Operating Temperature	-25		+85	°C
Supply Voltage for VDD_BAT	2.3	4.3	5.0	V
Logical high input voltage (for DI type pins)	0.85 x VDD_IO ^(*)		VDD_IO	V
Logical low input voltage (for DI type pins)	0		0.2 x VDD_IO	V

 $Note: VDD_IO$ is programmable as 3.3V or 1.8V individually.

4.1.3 Radio Frequency Characteristics

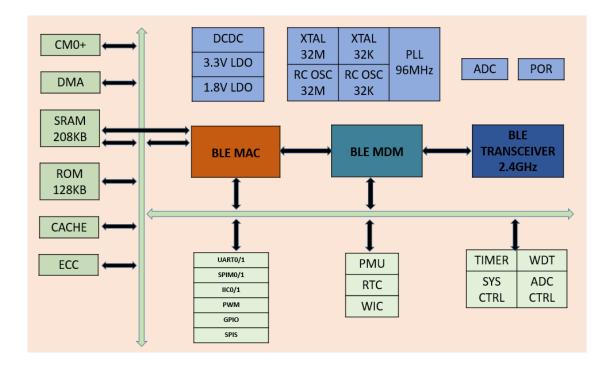
TA = 25° C, VDD = 4.3 V, Frequency=2.440 GHz

Parameter	Condition		Тур	Max	Unit
Dogoj vor Consitivity	At 1 Mbps RX Mode, 37 Byte payload length, BER<0.1%.	-93			dBm
Receiver Sensitivity	At 2 Mbps RX Mode, 37 Byte payload length, BER<0.1%	-90			dBm
Transmitter Outract Davis	Maximum RF Output Power at 0 dBm setting (Comply with Power Class 3 in Bluetooth Low Energy 5.0)	-4	-2	0	dBm
Transmitter Output Power	Maximum RF Output Power at 8 dBm setting (Comply with Power Class 1.5 in Bluetooth Low Energy 5.0)	5	6.5	8	dBm
	Receiver with integrated DC/DC Converter		4.3		mA
	0 dBm Transmitter with integrated DC/DC Converter		4.4		mA
	8 dBm Transmitter with integrated DC/DC Converter		26		mA
Current Consumption	Sleep with SRAM ($16\text{KB} \sim 208\text{KB}$) retention, 32.768KHz Crystal Clock	2.5		6	uA
	Average current during 1.28 sec active (broadcasting ADV) /sleep (SRAM 208 KB retention) cycle time		18		uA
	CPU Standby with 16MHz Clock running		1.5		mA

4.2 Block diagram

The block diagram of RF08 is shown below.





4.3 System blocks

CPU: The processor is an entry-level 32-bit processor designed for a broad range of embedded applications. It offers significant benefits to developers, including:

- A simple architecture that is easy to learn and program.
- Ultra-low power, energy-efficient operation.
- Excellent code density.
- Deterministic, high-performance interrupt handling.
- Platform security robustness, with integrated Memory Protection Unit (MPU).

BLE 5.0 MAC and PHY: This is the BLE MAC and PHY which is compatible with the BLE 5.0 protocol.

BLE RF module: This is the low power RF module which is compatible with the BLE 5.0 protocol.

Cache Controller: This is the 32bit 4 way read only cache controller which makes the CPU can run on the external flash with quard-SPI interface. The cache controller offers one cycle latency read access when the read from the CPU hit the cache. If cache miss, the cache controller is responsible to generate the SPI access command and fetch data from the external flash through quard-SPI interface.

AHB/APB bus matrix: This is the bus matrix which provides the data access channel between multiple AHB masters and multiple AHB/APB slaves. The access of different master slave pair does not affect each other which improve the data throughput of the system.

RAM controller: This is the SRAM controller which converts the AHB bus access to the 208KB SRAM



read/write command. Because one of the SRAM is shared with the exchange memory used by the BLE MAC, the SRAM controller is also responsible for the arbitration between the AHB bus and the BLE MAC.

ROM controller: This is the ROM controller which converts the AHB bus access to the 128KB ROM read command. The boot code and the BLE link layer stack are stored in the ROM.

ROM patch controller: This is the data patch controller for ROM data. It provides data patching for up to 16 ROM addresses.

System controller(CPU): This is the system controller which controls the clock generator, reset generator and the pin share logic of the system. It is also responsible for frequency calibration of the 32KHz clock from RC oscillator.

DMA controller: This is the DMA controller which provides directly data access channel between the SRAM and peripheral interfaces. There are 6 DMA channels implemented in the DMA controller.

ADC controller: This is the ADC controller which provides the data channel between the ADC and the APB bus. It supports both one time ADC sample and continuous ADC sample. It also supports DMA access by the DMA controller in the continuous sampling mode.

ECC engine: This is the ECC codec for the encrypt transmission of BLE. It provides hardware fast ECC calculation which costs less than 50ms for single ECC calculation.

Pin share controller: This is the pin share logic which provides flexible pin share scheme for different customers. The pin share logic is controlled by the system controller(CPU).

Clock generator(CPU): This is the clock generator which provides clock for all of the modules in the CPU power domain. It implements the clock divider, clock mux/switch and architecture clock gating for the CPU power domain.

Reset generator(CPU): This is the reset generator which provides the reset for all of the modules in the CPU power domain. It implements the reset synchronizer and the software reset logic for the CPU power domain.

UART2AHB: This is the UART interface module which provides the access channel to all of the system address space for the external UART controller. It can provide the access channel without the help of the CPU which means that even if the CPU does not work correctly, the external UART controller can access all the registers and memory space. It is mainly for debug.

Timer: This is the timer counter which is counting in a frequency programmable clock. There are two independent timer counters implemented.



Watch dog: This is the watch dog controller for the system, which can work in two modes: system reset mode and interrupt followed by system reset mode. The watch dog can prevent system from entering some dead status by interrupt and reset the system if the system does not kick the watch dog for a long time.

System controller(PER): This is the system controller which controls the clock generator, reset generator of the PER power domain.

Clock generator(PER): This is the clock generator which provides the clock for all of the modules in the PER power domain. It implements the clock divider, clock mux/switch and architecture clock gating for the PER power domain.

Reset generator(PER): This is the reset generator which provides the reset for all of the modules in the PER power domain. It implements the reset synchronizer and the software reset logic for the PER power domain.

UART interface controller(UARTO/UART1): Asynchronous serial interface controller with throughput up to 2Mbps. UART0 supports flow control and UART1 does not. Both of the UART interface controller support DMA access by DMA controller.

IIC interface controller(IICO/IIC1): This is the IIC interface controller which can be programmed to be master or slave. It supports DMA access by DMA controller.

SPI master interface controller(SPIM0/SPIM1): This is the SPI master interface with one bit data input and one bit data output and two bit chip select. The maximum throughput is 24Mbps. It supports DMA access by DMA controller.

SPI slave interface controller(SPIS): This is the SPI slave interface with one bit data input and one bit data output. The maximum throughput is 6Mbps. It supports DMA access by DMA controller.

PWM controller: This is the PWM waveform generator which generates 5 independent PWM output signal. The frequency and the duty cycle of the PWM signal are programmable.

GPIO controller: This is the general purpose IO controller which implements 30 GPIOs. The direction and output value are both programmable. And also the interrupt mode is programmable to edge and level.

Power management unit(PMU): This is the power management controller of the system which controls the power up and power down flow for each power domain. All of the DCDC/ /LDO are controlled by PMU according to the internal FSM of the PMU.



Wakeup interrupt controller(WIC): The wakeup interrupt controller monitor the wakeup interrupts and inform the PMU to power up the system if necessary. The wakeup controller also wakeup CPU after the system has been powered up.

Mode controller: The mode controller monitor the boot select IO value during the system power up reset active period and inform the CPU from which interface the CPU can get the boot loader and the IO voltage.

Pad ring: All the digital IO cell is implemented in this module.

Power PWM controller: This controller is used to control the power output. The power output can be set to on or off. And also the power output can be set to on for some time and off for some time just like a PWM waveform.

Real time controller: This is the real time timer for the system.

System controller(AWO): This is the system controller which controls the clock generator, reset generator, power PWM, PMU, pad ring of the AWO power domain. The IO retention function is also implemented in this module.

Clock generator(AWO): This is the clock generator which provides all the clock for the AWO power domain and all the other power domain. It implements the clock divider, clock mux/switch and architecture clock gating for the AWO power domain.

Reset generator(AWO): This is the reset generator which provides all the reset for the AWO power domain and all the other power domain. It implements the reset synchronizer and the software reset logic for the AWO power domain.

4.4 Function mode

RF08 has two functional modes of operation: Mirrored mode and Cached mode.

In Mirrored mode, the system code is mirrored from the external device to the system SRAM, and CPU is running on the system SRAM. In this mode cache controller is disabled. And the 16KB SRAM used by the cache controller can be used as the normal system SRAM.

In Cached mode, the system code is stored in the external flash, and CPU is running on the external flash. In this mode cache controller is enabled and the 16KB SRAM used by the cache controller can not be used as the normal system SRAM.

Cache mode is used only when the system SRAM is not big enough for system running. Cache mode



will cost more power than the mirrored mode and the performance of the CPU in cache mode is much worse than it is in the mirrored mode.

4.5 System boot sequence

After power up, power up reset will hold low for some time. Then after the power up reset is released, CPU will start to execute code from address 0x0. No address remapping is implemented in RF08 and ROM is always addressed at address 0x0. So after power up the boot sequence in the ROM is executed by CPU.

By default, all of the power sources are powered up after power on reset, and the 32MHz crystal and 32KHz RC oscillator are active. PLL is off by default. 32MHz clock is the main clock source of the system. CPU is working on 32MHz by default.

RF08 can boot from flash interface or UART interface. The IO voltage of the boot interface can be 1.8V or 3.3V. This is decided by two boot select pins. The two boot select pin shall be pulled up or pulled down to predefined value during power on reset period. The value of the boot select pins are latched to the internal boot registers during the power on reset period and be read by the CPU at the beginning of the boot sequence. Then CPU can decide which interface shall boot from and how much is the IO voltage level of the interface by reading the boot registers implemented in the system controller. The clock frequency of flash interface during boot period is 8MHz and the data rate of the UART interface during boot period is 115200bps. If boot from UART then P12 is used as TX data of UART interface and P13 is used as the RX data of UART interface.

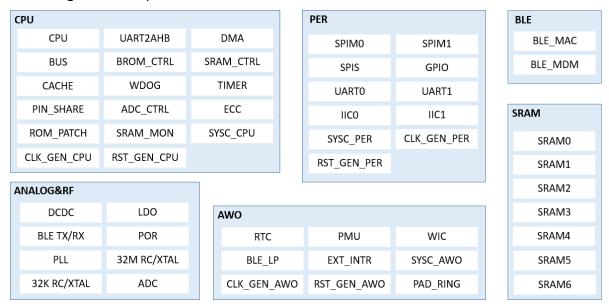
The decode logic of the boot select pin is shown below:

P16 is pulled down means boot from flash, P16 is pulled up means boot from UARTO(P12/P13). P23 is pulled down means IO voltage is 1.8V, P23 is pulled up means IO voltage is 3.3V. The default IO voltage is 1.8V.



4.6 Power domain

The block diagram of the power domain of RF08 is shown below:



RF08 is composed of 6 power domains which are CPU, PER, BLE, AWO, SRAM and ANALOG.

ANALOG power domain includes all of the analog and RF submodules and each analog and RF submodule is a dedicated sub power domain and can be powered on/off separately.

The SRAM power domain includes all of the 208kB system SRAM and is divided into 7 SRAM blocks. The size of each SRAM block is 32kB except the last block which is 16kB. Each of the 7 SRAM blocks is a dedicated sub power domain and can be powered on/off separately. The address mapping for the 7 SRAM blocks is shown below:

	start address	end address
SRAM0	0x100000	0x107FFF
SRAM1	0x108000	0x10FFFF
SRAM2	0x110000	0x107FFF
SRAM3	0x118000	0x11FFFF
SRAM4	0x120000	0x127FFF
SRAM5	0x128000	0x12FFFF
SRAM6	0x130000	0x133FFF

The PER power domain includes all of the digital peripheral interface modules. The PER power domain can work under 0.9V or 1.1V. The PER power domain can be powered off.

The BLE power domain includes BLE MAC and BLE PHY. The BLE power domain can work under 0.9V or 1.1V. The BLE power domain can be powered off.



The CPU power domain includes the core system which includes CPU, DMA, SRAM controller, bus matrix, cache controller, ECC module, system timer and system watch dog. CPU power domain can work under 0.9V or 1.1V. The CPU power domain can be powered off.

The AWO power domain includes the power management module, the IO ring, and the logic which can wake up system from sleep status which includes RTC, BLE low power counter, external interrupt controller. The AWO power domain can not be powered off. AWO power can only work under 0.9V.

All of the other power domains except the AWO and ANALOG power domain work under the same voltage in active mode. Under inactive mode (retention mode) the voltage of SRAM can be programmed to be less than 0.9V to save leakage power of SRAM. Each of the BLE/PER/SRAM* power domains can be powered off independently. And if CPU is powered off, BLE and PER must be powered off and SRAM* must be powered off or be set to retention status. The power on and power off sequence is controlled by hardware FSM and triggered by software.

RF08 has 6 power modes which are described in the table below:

power		AW				SRA	ANAL
mode	description	0	CPU	PER	BLE	M	OG
	AWO is working						
	CPU is working. The working						
	frequency of CPU is more than						
	32MHz, and CPU is working under						
	1.1V						
	at least one of the SRAM is						
	working(power on)						
	all of the other power domain is						
ACTIVE	on/off programmable by CPU	ON	ON	Р	Р	Р	Р
	AWO is working						
	CPU is working. The working						
	frequency of CPU is equal to or less						
	than 32MHz, and CPU is working						
	under 0.9V						
	at least one of the SRAM is						
	working(power on)						
ACTIVE	all of the other power domain is						
LOW	on/off programmable by CPU	ON	ON	Р	Р	Р	Р
	AWO is working						
	CPU is clock gated and the working						
	voltage of CPU is 1.1V						
SLEEP	at least one of the SRAM is	ON	ON	Р	Р	Р	Р



power		AW				SRA	ANAL
mode	description	0	CPU	PER	BLE	M	OG
	working(power on)						
	all the other power domain is						
	on/off programmable by CPU						
	AWO is working						
	CPU is clock gated and the working						
	voltage of CPU is 0.9V						
	at least one of the SRAM is						
	working(power on)						
SLEEP	all the other power domain is						
LOW	on/off programmable by CPU	ON	ON	Р	Р	Р	Р
	AWO is working under 32KHz						
	CPU, PER and BLE are powered off						
	At least one of the SRAM is in						
EXTEND	retention state						
ED	All of the other power domain is					ON/O	
SLEEP	power off	ON	OFF	OFF	OFF	FF	OFF
	PD_AWO is working under 32KHz						
	CPU, PER and BLE are powered off						
	All of the SRAM are off						
DEEP	All of the other power domain is						
SLEEP	power off	ON	OFF	OFF	OFF	OFF	OFF

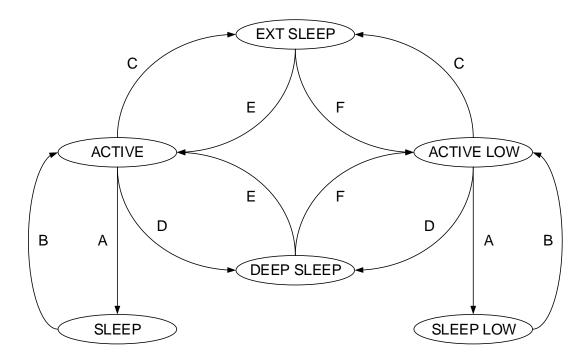
Note:

ON: power on OFF: power off

P: ON/OFF programmable

The power state machine of the power states is shown in the block diagram below:





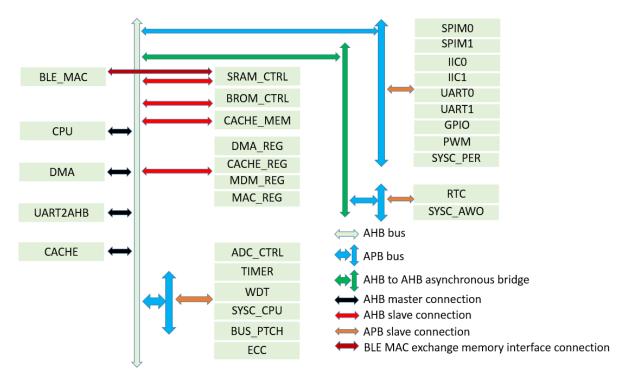
The power state transfer condition in the above diagram is shown in the table below:

	<u> </u>							
Α	CPU execute WFI with DEEP_SLEEP bit set to low							
В	any non-masked interrupt is active							
С	CPU execute WFI with DEEP_SLEEP bit set to high, and not all of the							
	active SRAM is powered off together with CPU							
D	CPU execute WFI with DEEP_SLEEP bit set to high, and all of the active							
	SRAM are powered off together with CPU							
E	Any of the external interrupt, BLE low power interrupt, RTC interrupt is							
	active and CPU is waked up with the register VDD_VOLTAGE is set to low							
	which means CPU will work under 1.1V after wake up							
F	Any of the external interrupt, BLE low power interrupt, RTC interrupt is							
	active and CPU is waked up with the register VDD_VOLTAGE is set to							
	high which means CPU will work under 0.9V after wake up							
note	note: register VDD_VOLTAGE is a programmable register in AWO power							
don	nain which address is 0x20201048[0]							

5 Bus architecture

The bus architecture of RF08 is shown below.





The system bus is based on AHB and APB. The data width of the bus is 32 bits. The AHB bus works under the same frequency with CPU. The maximum frequency of AHB bus is 96MHz and programmable with 16MHz step. The maximum frequency of APB bus is one half of the frequency of AHB bus which is 48MHz. The frequency of APB bus is the integer division of the frequency of the AHB bus. There are altogether 4 AHB masters which are CPU, DMA, UART2AHB and CACHE. The exchange memory(EM/32KB) required by the BLE MAC is 32KB and shared with system SRAM. So the BLE MAC can access the SRAM directly through an internal interface. BLE MAC has the highest priority when any other AHB master accesses the same SRAM with BLE MAC at the same time. The accessibility and the priority of the AHB masters to the slaves is shown in the table below:

	BROM_CTRL	CACHE_MEM	SRAM_CTRL	OTHER	AWO_REG
CPU	0	0	1	0	0
UART2AHB	X	X	2	1	1
DMA	Х	Х	3	2	Х
CACHE	Х	Х	Х	Х	Х
BLE_MAC	Х	Х	0	Х	Х

In this table, X means the master can not access the slave. Number means the master can access the slave and 0 has the highest priority. The cache size in the bus diagram is 16kB which is shared with the system SRAM. When cache is enable, the last 16kB system SRAM address space must not be accessed by CPU or other bus master. The last 16kB SRAM is used as the cache SRAM at that time.

The size of the system SRAM is 208kB and the address starts with 0x100000. The system SRAM is composed of 7 sub SRAM blocks as described in chapter 4.5. And if one of the SRAM sub block is not needed any more in the system it can be powered of to save power. BLE_MAC can only access



the fifth SRAM sub block which address starts with 0x128000. When the CPU is running on the external flash, the flash controller must be enabled and the last SRAM sub block is used as the cache and can not accessed by the other AHB master.



6 Address mapping

The address mapping of RF08 is shown below:

addr zone		s is snown below	start	end	space	
brom			0x00000000	0x0001FFFF	128kB	
reserved			0x00020000	0x000FFFFF	896kB	
sram			0x00100000	0x00133FFF	208kB	
reserved			0x00134000	0x001FFFFF	816kB	
reserved			0x00200000	0x007FFFF	6MB	
cache			0x00800000	0x00FFFFF	8MB	
reserved			0x01000000	0x1FFFFFFF	496MB	
reserved			0x20000000	0x200FFFFF	1MB	
		ble_mac_reg	0x20100000	0x2010FFFF	64kB	
		ble_mdm_reg	0x20110000	0x2011FFFF	64kB	
	ahb	dma_reg	0x20120000	0x20120FFF	4kB	
		cache_reg	0x20121000	0x20121FFF	4kB	
		reserved	0x20122000	0x2012FFFF	56kB	
		timer	0x20130000	0x20130FFF	4kB	
	apb0	wdt	0x20131000	0x20131FFF	4kB	
		sysc_bus	0x20132000	0x20132FFF	4kB	
		bus_ptch	0x20133000	0x20133FFF	4kB	
		ecc	0x20134000	0x20134FFF	4kB	
		reserved	0x20135000	0x20135FFF	4kB	
peripheral		adc_ctrl	0x20136000	0x20136FFF	4kB	
periprierai		reserved	0x20137000	0x2013FFFF	36kB	
		spim0	0x20140000	0x20140FFF	4kB	
		spim1	0x20141000	0x20141FFF	4kB	
		spis	0x20142000	0x20142FFF	4kB	
		uart0	0x20143000	0x20143FFF	4kB	
		uart1	0x20144000	0x20144FFF	4kB	
	apb3	iic0	0x20145000	0x20145FFF	4kB	
		iic1	0x20146000	0x20146FFF	4kB	
		pwm	0x20147000	0x20147FFF	4kB	
		gpio	0x20148000	0x20148FFF	4kB	
	sysc_per		0x20149000	0x20149FFF	4kB	
		reserved	0x2014A000	0x2014FFFF	24kB	
reserved			0x20150000	0x200FFFFF	704kB	
3WO	apb1	rtc	0x20200000	0x20200FFF	4kB	
awo	αρυτ	sysc_awo	0x20201000	0x20201FFF	4kB	



7 IO Mux

The IO mux table of RF08 is shown below.

pad		func0			func	1	func2		func3			func4			
name	Ю	sig_name	io	sig_name	io	en	sig_name	io	en	sig_name	io	en	sig_name	io	en
P00	В	swck	- 1	gpio[0]	В	gpio00_en									
P01	В	swd	В	gpio[1]	В	gpio01_en									
P02	В	gpio[2]	В	spim0_cs1	0	spim0_cs1_en				func_io[0]	В	func_io_en[0]			
P03	В	gpio[3]	В	spim0_cs0	0	spim0_en	spis_cs	I	spis_en	func_io[1]	В	func_io_en[1]			
P04	В	gpio[4]	В	spim0_clk	0	spim0_en	spis_clk	I	spis_en	func_io[2]	В	func_io_en[2]			
P05	В	gpio[5]	В	spim0_miso	I	spim0_en	spis_miso	0	spis_en	func_io[3]	В	func_io_en[3]			
P06	В	gpio[6]	В	spim0_mosi	0	spim0_en	spis_mosi	I	spis_en	func_io[4]	В	func_io_en[4]			
P08	В	gpio[8]	В	spim1_cs0	0	spim1_en	ble_mac_dbg[1]	0	ble_mac_dbg_en[1]	func_io[6]	В	func_io_en[6]	rfif_rx[0]	0	rfif_en
P10	В	gpio[10]	В	spim1_miso	I	spim1_en	ble_mac_dbg[3]	0	ble_mac_dbg_en[3]	func_io[8]	В	func_io_en[8]	rfif_tx[0]	ı	rfif_en
P11	В	gpio[11]	В	spim1_mosi	0	spim1_en	ble_mac_dbg[4]	0	ble_mac_dbg_en[4]	func_io[9]	В	func_io_en[9]	rfif_tx[1]	ı	rfif_en
P12	В	uart2ahb_txd	0	gpio[12]	В	gpio14_en	ble_mac_dbg[5]	0	ble_mac_dbg_en[5]	func_io[10]	В	func_io_en[10]	rfif_tx[2]	1	rfif_en
P13	В	uart2ahb_rxd	- 1	gpio[13]	В	gpio15_en	ble_mac_dbg[6]	0	ble_mac_dbg_en[6]	func_io[11]	В	func_io_en[11]	rfif_tx[3]	1	rfif_en
P15	В	gpio[15]	В							func_io[13]	В	func_io_en[13]	rfif_tx[5]	1	rfif_en
P16	В	gpio[16]	В							func_io[14]	В	func_io_en[14]			
P17	В	gpio[17]	В							func_io[15]	В	func_io_en[15]	rfif_tx[6]	ı	rfif_en
P21	В	gpio[21]	В							func_io[19]	В	func_io_en[19]	rfif_tx[10]	ı	rfif_en
P22	В	gpio[22]	В							func_io[20]	В	func_io_en[20]	rfif_tx[11]	ı	rfif_en
P23	В	gpio[23]	В							func_io[21]	В	func_io_en[21]			



The programmable registers for the enable signals are listed below:

0x20132020[23:16]	ble_mac_dbg_en
0x20132020 [13]	rfif_en
0x20132020 [12]	gpio15_en
0x20132020 [10]	gpio01_en
0x20132020 [9]	gpio00_en
0x20132020 [8]	spis_en
0x20132020 [7]	spim1_cs1_en
0x20132020 [6]	spim1_en
0x20132020 [5]	spim0_cs1_en
0x20132020 [4]	spim0_en
0x20132024[21:0]	func_io_en

The func_io is shared by many interface modules and each bit of the func_io can be programmed to act as any of the shared function. The share table is listed below:

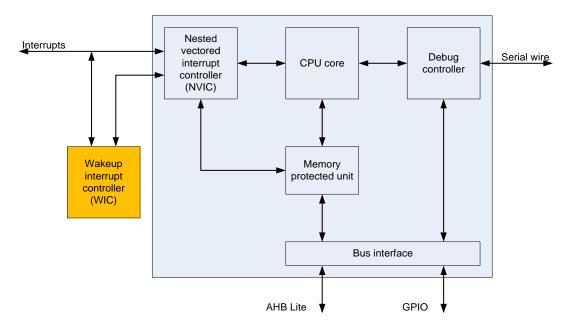
signal name	io	idx
uart0_txd	0	0
uart0_rxd	1	1
uart0_cts	1	2
uart0_rts	0	3
uart1_txd	0	4
uart1_rxd	I	5
iic0_scl	В	6
iic0_sda	В	7
iic1_scl	В	8
iic1_sda	В	9
pwm0	0	10
pwm1	0	11
pwm2	0	12
pwm3	0	13
pwm4	0	14



8 CPU

8.1 General description

RF08 integrates CPU. The processor is an ultra-low power 32-bit processor designed for a broad range of embedded applications. The block diagram of processor is shown below:



The processor is built on a highly area and power optimized 32-bit processor core, with a 2-stage pipeline von Neumann architecture. The processor delivers exceptional energy efficiency through a small but powerful instruction set and extensively optimized design, providing high-end processing hardware including a single-cycle multiplier.

The processor is based on the 16-bit Thumb instruction set and includes Thumb-2 technology. This provides the exceptional performance expected of a modern 32-bit architecture, with a higher code density than other 8-bit and 16-bit microcontrollers.

The processer integrates a nested vectored interrupt controller, a debug controller and a memory protect unit.



9 Cache controller

9.1 Feature List

- Zero wait cycle when cache hit
- 8MB cachable address space with the start address programmable
- 16KB cache data size which is shared with the system SRAM
- Supports cache flush command
- 4 Way cache with LRU algorithm
- Read only cache
- 32 bytes cache line size

10 ADC

10.1 General description

The RF08 is equipped with a low power 10-bit general purpose Analog-to-Digital Converter (GPADC). It can operate in unipolar (single ended) mode as well as in bipolar (differential) mode. The ADC has its own voltage regulators (LDO) of 3V. The full scale reference voltage of GPADC is optional set from 2.2V to 2.8V.

Features

- 10-bit dynamic ADC with average capability
- Maximum sampling rate 2 Msample/s at 96MHz ADC clock
- Single-ended as well as differential input with two input scales
- Six single-ended or two differential external input channels
- Oversampling up to 64 steps providing effectively up to 12 bits resolution
- Support battery monitoring function from 2.0V to 5.5V
- Support temperature Sensing function from -40 to 125 degree
- DMA support



11 SPI master

11.1 Feature list

- APB interface with 32 bit data bus
- Supports 1wire mode, one wire of TX data and one wire of RX data
- Supports DMA interface
- 32 words RX and TX data FIFO
- Programmable SPI interface clock, maximum frequency is 24MHz
- Compliant with Motorola SPI interface
- Programmable SPI data size: 4 bits to 32 bits
- SPI mode programmable(phase and clock edge)
- Two chip select output
- Programmable RX data sample edge



12 SPI slave

12.1 Feature list

- APB interface with 32 bit data bus
- Supports 1wire mode, one wire of TX data and one wire of RX data
- Supports DMA interface
- 32 words RX and TX data FIFO
- Programmable SPI interface clock, maximum frequency is 2MHz
- Compliant with Motorola SPI interface
- Programmable SPI data size: 4 bits to 32 bits
- SPI mode programmable(phase and clock edge)
- Programmable RX data sample edge

13 UART

13.1 Feature list

- 32 bytes transmit and receive FIFO
- Hardware flow control(UARTO only)
- IRDA 1.0 SIR mode support(UARTO only)
- Programmable baud rate
- Programmable frame format of data bits per frame
- Optional parity bit and programmable number of stop bits
- DMA transmission



14 IIC

14.1 Feature list

- Two-wire IIC serial interface consists of a serial data line (SDA) and a serial clock (SCL)
- Three speeds are supported: Standard mode (0 to 100Kbps); Fast mode (400Kbps) or High-speed mode (3.4Mbps)
- Master OR slave IIC operation
- 7- or 10-bit addressing
- 7- or 10-bit combined format transfers
- Transmit and receive FIFO
- Handles Bit and Byte waiting at all bus speeds
- Supports DMA transfer
- Programmable SDA hold time



15 Power management

The power management unit (PMU) in RF08 comprises a DC-DC Buck Converter, various LDOs for the different power domains of the system. The PMU is capable of supplying external devices even during RF08 in sleep mode.

Features

- DC-DC Buck Converter with excellent 93% efficiency
- Programmable DC-DC converter output charging sequence
- One LDO output up to 3.3 V with up to 50 mA load capability
- DC-DC converter automatically on/off control during in sleep mode
- Active and Sleep mode current limited LDOs
- Use of small external components
- Supply of external rails (V33, VDD1V8) while in Sleep mode

16 DC/DC Buck Converter

Two DC/DC Buck Converter modes are designed for RF08. One is DC/DC Converter ON and the other is DC/DC Converter Bypass. RF08 will automatically enter DC/DC Converter ON mode within 150 us while CPU is active. And DC/DC Converter will be bypass mode during CPU in sleep mode.

 $(Ta = -40^{\circ}C \sim +85^{\circ}C, 2.3V \leq VBAT \leq 5V)$

Item	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
	Input Voltage		2.3		4.75	V
				1.4		V
		DC/DC Converter On		1.3		V
DC/DC	Outrout Valtage	(Default 1.4V)		1.2		V
DC/DC Converter	Output Voltage			1.1		V
Converter		DC/DC Converter		VBAT-		
		Bypass		0.3		V
	Quiescent Current	DC/DC Converter On		100		uA
	Start-up Time	DC/DC Converter On		120		usec



17 LDO

RF08 provides several LDOs to external power supply, including two 3.3V LDO and one 1.8V LDO. The LDO for external use can be configured as active even in sleep mode. The LDO characteristics are listed below.

(Ta = -40° C $\sim +105^{\circ}$ C , 2.3V \leq VBAT \leq 5.0V)

Item	Parameter	MIN.	TYP.	MAX.	Unit
1.8V LDO	Output Current			40	mA
	Output Voltage at 96MHz > 10mA		1.8		V

(Ta = -40° C ~ $+105^{\circ}$ C , $2.3V \leq VBAT \leq 5.0V$)

Item	Parameter	MIN.	TYP.	MAX.	Unit
3.0V LDO_1	Output Current			25	mA
	Output Voltage		3.0		V

(Ta = -40° C $\sim +105^{\circ}$ C , 2.3V \leq VBAT \leq 5.0V)

Item	Parameter	MIN.	TYP.	MAX.	Unit
3.0V LDO_2	Output Current			50	mA
	Output Voltage		3.0		V

18 32MHz Crystal Oscillator

32MHz Crystal Oscillator characteristics are listed below. Also, frequency compensation, programmable level of frequency compensation capacitors will be implemented to

cover 32MHz Crystal variation, aging ... over temperature range -40°C $^{\sim}$ +105°C.

(Ta = -40° C ~ $+105^{\circ}$ C , $2.3V \le VBAT \le 5V$)

Item	Parameter	MIN.	TYP.	MAX.	Unit
	Oscillation frequency		32		MHz
	Frequency offset	-20		20	ppm
32MHz Crystal Oscillator	Startup time			150	μs
	Shunt Capacitor (with NDK NX3225SA)			10	pF



19 32MHz RC Oscillator

32MHz RC Oscillator characteristics are listed below.

 $(Ta = -40^{\circ}C \sim +105^{\circ}C, 2.3V \leq VBAT \leq 5V)$

Item	Parameter	MIN.	TYP.	MAX.	Unit
Internal 32MHz RC	Oscillation frequency		32		MHz
Oscillator	Startup time		-	20	μs

20 32KHz Crystal Oscillator

32KHz Crystal Oscillator characteristics are listed below.

(Ta = -40° C $\sim +105^{\circ}$ C , $2.3V \leq VBAT \leq 5V$)

Item	Parameter	MIN.	TYP.	MAX.	Unit
22 760/41	Oscillation frequency		32.768		KHz
32.768KHz Crystal Oscillator	Frequency offset	-20		20	ppm
	Series Resistor		10		МΩ
	Shunt Capacitor		33		pF

21 32KHz RC Oscillator

32KHz RC Oscillator characteristics are listed below

(Ta = -40°C \sim +105°C , $~2.3V~\leq~VBAT \leq~5V$)

Item	Parameter	MIN.	TYP.	MAX.	Unit
	Oscillation frequency		32		KHz
Internal	Frequency offset after calibrated	-500		500	nnm
32KHz RC	by 32MHz Crystal Oscillator	-300		300	ppm
Oscillator	Chip-to-chip Variation from -40°C	10	-	100	KHz
	~+85°C, 2.3V~5V				



22 PLL

RF08 provides alternative 96/80/64/48/32/16 MHz system clock. Changing this system's clock can be done within 300 us without affecting the operation of the chip. This PLL dissipates additional 0.4 mA when operating at 96 MHz.

(Ta = -40° C ~ $+105^{\circ}$ C , $2.3V \leq VBAT \leq 5V$)

Item	Parameter	MIN.	TYP.	MAX.	Unit
PLL	Output Clock (Default 96MHz)		96		MHz
			80		MHz
			64		MHz
			48		MHz
			32		MHz
			16		MHz
	Reference Clock		16		MHz
	Stable time			300	μs